

# HMC478ST89 / 478ST89E

RoHS Presider's Kit

v05.0710

## **Typical Applications**

The HMC478ST89 / HMC478ST89E is an ideal RF/IF gain block & LO or PA driver:

- Cellular / PCS / 3G
- Fixed Wireless & WLAN
- CATV, Cable Modem & DBS
- Microwave Radio & Test Equipment

#### **Functional Diagram**



# SiGe HBT GAIN BLOCK MMIC AMPLIFIER, DC - 4 GHz

#### Features

P1dB Output Power: +18 dBm Gain: 22 dB Output IP3: +30 dBm Cascadable 50 Ohm I/Os Single Supply: +5V to +8V Industry Standard SOT89 Package Robust 1,000V ESD, Class 1C Included in the HMC-DK001 Designer's Kit

## **General Description**

The HMC478ST89 & HMC478ST89E are SiGe Heterojunction Bipolar Transistor (HBT) Gain Block MMIC SMT amplifiers covering DC to 4 GHz. Packaged in an industry standard SOT89, the amplifier can be used as a cascadable 50 Ohm RF/IF gain stage as well as a LO or PA driver with up to +20 dBm output power. The HMC478ST89(E) offers 22 dB of gain with a +30 dBm output IP3 at 850 MHz while requiring only 62mA from a single positive supply. The Darlington feedback pair used results in reduced sensitivity to normal process variations and excellent gain stability over temperature while requiring a minimal number of external bias components.

## Electrical Specifications, Vs = 5V, Rbias = 18 Ohm, $T_A = +25^{\circ}$ C

Parameter		Min.	Тур.	Max.	Units
	DC - 1.0 GHz	19	22		dB
Gain	1.0 - 2.0 GHz	16	19		dB
Gain	2.0 - 3.0 GHz	13	16		dB
	3.0 - 4.0 GHz	11	14		dB
Gain Variation Over Temperature	DC - 4 GHz		0.015	0.02	dB/ °C
	DC - 1.0 GHz		15		dB
Input Return Loss	1.0 - 3.0 GHz		10		dB
	3.0 - 4.0 GHz		13		dB
Output Datum Lana	DC - 3.0 GHz		13		dB
Output Return Loss	3.0 - 4.0 GHz		15		dB
Reverse Isolation	DC - 4 GHz		20		dB
	0.5 - 1.0 GHz	15	18		dBm
Output Power for 1 dB Compression (P1dB)	1.0 - 2.0 GHz	13	16		dBm
Output Fower for T dB Compression (F TdB)	2.0 - 3.0 GHz	10	13		dBm
	3.0 - 4.0 GHz	8	11		dBm
Output Third Order Intersent (ID2)	0.5 - 2.0 GHz		30		dBm
Output Third Order Intercept (IP3) (Pout= 0 dBm per tone, 1 MHz spacing)	2.0 - 3.0 GHz		28		dBm
	3.0 - 4.0 GHz		25		dBm
Neise Figure	DC - 2.0 GHz		3		dB
Noise Figure	2.0 - 4.0 GHz		4		dB
Supply Current (Icq)			62	82	mA

Note: Data taken with broadband bias tee on device output.

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#### Broadband Gain & Return Loss



Input Return Loss vs. Temperature



**Reverse Isolation vs. Temperature** 



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# Gain vs. Temperature



## Output Return Loss vs. Temperature



# Noise Figure vs. Temperature



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#### P1dB vs. Temperature



Output IP3 vs. Temperature



Vcc vs. Icc Over Temperature for Fixed Vs= 5V, RBIAS= 18 Ohms



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#### Psat vs. Temperature



#### Gain, Power & Output IP3 vs. Supply Voltage for Constant Icc= 62 mA @ 850 MHz



Gain, Power & Output IP3 vs. Supply Voltage for Rs = 18 Ohms @ 850 MHz



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# Absolute Maximum Ratings

Collector Bias Voltage (Vcc)	+6 Vdc
RF Input Power (RFIN)(Vcc = +4.2 Vdc)	+5 dBm
Junction Temperature	150 °C
Continuous Pdiss (T = 85 °C) (derate 9.5 mW/°C above 85 °C)	0.615 W
Thermal Resistance (junction to lead)	105.6 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C
ESD Sensitivity (HBM)	Class 1C



#### ELECTROSTATIC SENSITIVE DEVICE OBSERVE HANDLING PRECAUTIONS

# **Outline Drawing**







NOTES:

1. PACKAGE BODY MATERIAL:

MOLDING COMPOUND MP-180S OR EQUIVALENT.

2. LEAD MATERIAL: Cu w/ Ag SPOT PLATING.

3. LEAD PLATING: 100% MATTE TIN.

4. DIMENSIONS ARE IN INCHES [MILLIMETERS]

ADIMENSION DOES NOT INCLUDE MOLDFLASH OF 0.15mm PER SIDE.

7. ALL GROUND LEADS MUST BE SOLDERED TO PCB RF GROUND.

#### Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking <sup>[3]</sup>
HMC478ST89	Low Stress Injection Molded Plastic	Sn/Pb Solder	MSL1 <sup>[1]</sup>	H478 XXXX
HMC478ST89E	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1 <sup>[2]</sup>	<u>H478</u> XXXX

[1] Max peak reflow temperature of 235 °C

[2] Max peak reflow temperature of 260 °C

[3] 4-Digit lot number XXXX

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#### **Pin Descriptions**

Pin Number	Function	Description	Interface Schematic
1	RFIN	This pin is DC coupled. An off chip DC blocking capacitor is required.	RFOUT
3	RFOUT	RF output and DC Bias (Vcc) for the output stage.	
2, 4	GND	These pins and package bottom must be connected to RF/DC ground.	

## **Application Circuit**



## Recommended Bias Resistor Values for Icc= 62 mA, Rbias= (Vs - Vcc) / Icc

Supply Voltage (Vs)	5V	6V	8V	
RBIAS VALUE	18 Ω	35 Ω	67 Ω	
RBIAS POWER RATING	1/8 W	1/4 W	1/2 W	

Note:

1. External blocking capacitors are required on RFIN and RFOUT.

2. RBIAS provides DC bias stability over temperature.

## **Recommended Component Values for Key Application Frequencies**

Component	Frequency (MHz)					
Component	50	900	1900	2200	2400	3500
L1	270 nH	56 nH	18 nH	18 nH	15 nH	8.2 nH
C1, C2	0.01 µF	100 pF				

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## **Evaluation PCB**



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# List of Materials for Evaluation PCB 110161 [1]

Item	Description	
J1 - J2	PC Mount SMA Connector	
J3 - J4	DC Pin	
C1 - C3	100 pF Capacitor, 0402 Pkg.	
C4	1000 pF Capacitor, 0603 Pkg.	
C5	2.2 µF Capacitor, Tantalum	
R1	Resistor, 1210 Pkg.	
L1	18 nH Inductor, 0603 Pkg.	
U1	HMC478ST89 / HMC478ST89E	
PCB [2]	108370 Evaluation PCB	

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350

The circuit board used in the final application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and package bottom should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation board should be mounted to an appropriate heat sink. The evaluation circuit board shown is available from Hittite upon request.

8 AMPLIFIERS - DRIVER & GAIN BLOCK - SMT

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